

Yanfeng Ge

List of Publications by Year in descending order

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papers

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623734

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41
times ranked

1386
citing authors

#	ARTICLE	IF	CITATIONS
1	First-principles demonstration of superconductivity at 280 K in hydrogen sulfide with low phosphorus substitution. <i>Physical Review B</i> , 2016, 93, .	3.2	95
2	Sulfur-Doped Black Phosphorus Field-Effect Transistors with Enhanced Stability. <i>ACS Applied Materials & Interfaces</i> , 2018, 10, 9663-9668.	8.0	93
3	The strain effect on superconductivity in phosphorene: a first-principles prediction. <i>New Journal of Physics</i> , 2015, 17, 035008.	2.9	72
4	Effect of doping and strain modulations on electron transport in monolayer MoS ₂ . <i>Physical Review B</i> , 2014, 90, .	3.2	56
5	Phonon-mediated superconductivity in silicene predicted by first-principles density functional calculations. <i>Europhysics Letters</i> , 2013, 104, 36001.	2.0	55
6	Hole-doped room-temperature superconductivity in H ₃ S _{1-x} Z (Z=C, Si). <i>Materials Today Physics</i> , 2020, 15, 100330.	6.0	53
7	High-temperature ferromagnetic semiconductors: Janus monolayer vanadium trihalides. <i>Physical Review B</i> , 2020, 101, .	3.2	45
8	Type-I and type-II nodal lines coexistence in the antiferromagnetic monolayer CrAs_2 . <i>Physical Review B</i> , 2018, 98, .	3.2	45
9	Pressure-induced phase transitions and superconductivity in a quasi-1-dimensional topological crystalline insulator $\text{In}_4\text{Bi}_4\text{Br}_4$. <i>Proceedings of the National Academy of Sciences of the United States of America</i> , 2019, 116, 17696-17700.	7.1	36
10	Phonon and electron transport in Janus monolayers based on InSe. <i>Journal of Physics Condensed Matter</i> , 2019, 31, 435501.	1.8	27
11	Two dimensional superconductors in electrides. <i>New Journal of Physics</i> , 2017, 19, 123020.	2.9	22
12	Two dimensional ferromagnetic semiconductor: monolayer CrGeS_3 . <i>Journal of Physics Condensed Matter</i> , 2020, 32, 015701.	1.8	20
13	Large thermoelectric power factor of high-mobility transition-metal dichalcogenides with Te_2 phase. <i>Physical Review Research</i> , 2020, 2, .	1.6	18
14	Strong phonon anharmonicity and low thermal conductivity of monolayer tin oxides driven by lone-pair electrons. <i>Applied Physics Letters</i> , 2019, 114, .	3.3	16
15	Phonon-limited electronic transport of two-dimensional ultrawide bandgap material h-BeO. <i>Applied Physics Letters</i> , 2020, 117, 123101.	3.3	13
16	Direct and indirect optical absorptions of cubic BAs and BSb. <i>Optics Express</i> , 2020, 28, 238.	3.4	13
17	Room-temperature superconductivity in boron- and nitrogen-doped lanthanum superhydride. <i>Physical Review B</i> , 2021, 104, .	3.2	13
18	A new kind of 2D topological insulators BiCN with a giant gap and its substrate effects. <i>Scientific Reports</i> , 2016, 6, 30003.	3.3	10

#	ARTICLE	IF	CITATIONS
19	Emergence of intrinsic superconductivity in monolayer W ₂ N ₃ . <i>Physical Review B</i> , 2021, 103, .	3.2	10
20	Superconductivity in the two-dimensional nonbenzenoid biphenylene sheet with Dirac cone. <i>2D Materials</i> , 2022, 9, 015035.	4.4	10
21	Tunable Electronic Structures in Wrinkled 2D Transition-Metal Trichalcogenide (TMT) HfTe ₃ Films. <i>Advanced Electronic Materials</i> , 2016, 2, 1600324.	5.1	9
22	Magnetic diversity in stable and metastable structures of CrAs. <i>Physical Review B</i> , 2017, 96, .	3.2	9
23	Strain-tunable magnetic order and electronic structure in 2D CrAsS ₄ . <i>Journal of Magnetism and Magnetic Materials</i> , 2020, 497, 165941.	2.3	8
24	Pressure-induced novel nitrogen-rich aluminum nitrides: AlN ₆ , Al ₂ N ₇ and AlN ₇ with polymeric nitrogen chains and rings. <i>Physical Chemistry Chemical Physics</i> , 2021, 23, 12350-12359.	2.8	8
25	Superconductivity in graphite-diamond hybrid. <i>Materials Today Physics</i> , 2022, 23, 100630.	6.0	7
26	Superconductivity in Li-intercalated bilayer arsenene and hole-doped monolayer arsenene: a first-principles prediction. <i>Journal of Physics Condensed Matter</i> , 2018, 30, 245701.	1.8	6
27	Modulation of heat transport in two-dimensional group-III chalcogenides. <i>Journal Physics D: Applied Physics</i> , 2020, 53, 185102.	2.8	6
28	Diverse magnetism in stable and metastable structures of CrTe. <i>Frontiers of Physics</i> , 2021, 16, 1.	5.0	6
29	Ternary FePSe ₃ Atomic Layers with Competitive Temperature Coefficient of Resistance for Uncooled Infrared Bolometers. <i>Advanced Materials Interfaces</i> , 2021, 8, 2100491.	3.7	6
30	Robust intrinsic half-metallic ferromagnetism in stable 2D single-layer MnAsS ₄ . <i>Journal of Physics Condensed Matter</i> , 2020, 32, 385803.	1.8	6
31	Electronic, magnetic, and optical properties of Mn-doped GaSb: A first-principles study. <i>Physica B: Condensed Matter</i> , 2019, 572, 225-229.	2.7	5
32	Hexagonal MASnI ₃ exhibiting strong absorption of ultraviolet photons. <i>Applied Physics Letters</i> , 2019, 114, .	3.3	5
33	Effects of layer stacking and strain on electronic transport in two-dimensional tin monoxide*. <i>Chinese Physics B</i> , 2019, 28, 077104.	1.4	4
34	Large Magnetic Anisotropy Energy and Robust Half-Metallic Ferromagnetism in 2D MnXSe ₄ (X = As, Sb). <i>Annalen Der Physik</i> , 2020, 532, 2000365.	2.4	4
35	Strain tunable intrinsic ferromagnetic in 2D square CrBr ₂ . <i>AIP Advances</i> , 2021, 11, 115220.	1.3	4
36	Prediction of Chalcogen-Doped VCl ₃ Monolayers as 2D Ferromagnetic Semiconductors with Enhanced Optical Absorption. <i>Annalen Der Physik</i> , 2021, 533, 2100064.	2.4	3

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37	Theoretical study of the structure and magnetism of Ga _{1-x} V _x Sb compounds for spintronic applications. Applied Physics Letters, 2020, 116, .	3.3	2
38	A New Type of Large- ϵ Quantum Spin Hall Insulator Material ZrSe ₅ . Physica Status Solidi (B): Basic Research, 2021, 258, 2100256.	1.5	2
39	High-performance electronic transport in the plane of 3D type-II Dirac semimetals. Journal of Physics Condensed Matter, 2017, 29, 415701.	1.8	1
40	Tuning of n-type doping by intercalation of group V and VII atoms in SnS ₂ bilayer. Materials Science in Semiconductor Processing, 2022, 145, 106649.	4.0	1
41	A First-Principles Study of the Structural, Magnetic, Optical Properties and Doping Effect in Chromium Arsenide. Physica Status Solidi (B): Basic Research, 0, , 2200062.	1.5	0